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Vishay Semiconductor/Diodes Division VS-175BGQ030HF4

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Distributor of Vishay Semiconductor/Diodes Division: Excellent Integrated System Limite Datasheet of VS-175BGQ030HF4 - DIODE SCHOTTKY 175A 30V POWERTAB

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VS-175BGQ030HF4

Vishay Semiconductors

High Performance Schottky Rectifier, 175 A



PowerTab[®]

| PRODUCT SUMMARY | | | | |
|----------------------------------|------------------|--|--|--|
| Package | PowerTab® | | | |
| I _{F(AV)} | 175 A | | | |
| V _R | 30 V | | | |
| V _F at I _F | 0.52 V | | | |
| I _{RM} | 650 mA at 125 °C | | | |
| T _J max. | 150 °C | | | |
| Diode variation | Single die | | | |
| E _{AS} | 80 mJ | | | |

FEATURES

- 150 °C max. operating junction temperature
- High frequency operation
- Ultralow forward voltage drop
- Continuous high current operation
- Guard ring for enhanced ruggedness and long term reliability
- Screw mounting only
- AEC-Q101 qualified
- PowerTab[®] package
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-175BGQ030HF4 Schottky rectifier has been optimized for ultralow forward voltage drop specifically for low voltage output in high current AC/DC power supplies. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, reverse battery protection, and redundant power subsystems.

| MAJOR RATINGS AND CHARACTERISTICS | | | | | |
|-----------------------------------|-------------------------------|-------------|-------|--|--|
| SYMBOL | CHARACTERISTICS | VALUES | UNITS | | |
| . Rectangular waveform | | 175 | А | | |
| I _{F(AV)} | T _C | 97 | °C | | |
| V _{RRM} | | 30 | V | | |
| I _{FSM} | t _p = 5 μs sine | 7400 | А | | |
| V | 175 A _{pk} (typical) | 0.47 | V | | |
| V _F | TJ | 150 | °C | | |
| TJ | Range | -55 to +150 | °C | | |

| VOLTAGE RATINGS | | | | | |
|---|------------------|-----------------|-------|--|--|
| PARAMETER | SYMBOL | VS-175BGQ030HF4 | UNITS | | |
| Maximum DC reverse voltage V _R | | 30 | V | | |
| Maximum working peak reverse voltage | V _{RWM} | 50 | V | | |

| ABSOLUTE MAXIMUM RATINGS | | | | | | |
|--|--------------------|--|--|--------|-------|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | | VALUES | UNITS | |
| Maximum average forward current | I _{F(AV)} | 50 % duty cycle at T_C = 97 °C, rectangular waveform | | 175 | А | |
| Maximum peak one cycle non-repetitive surge current | | 5 µs sine or 3 µs rect. pulse | Following any rated load condition and with rated | 7400 | A | |
| | | 10 ms sine or 6 ms rect. pulse | V _{RRM} applied | 1400 | | |
| Non-repetitive avalanche energy | E _{AS} | T _J = 25 °C, I _{AS} = 12 A, L = 1.12 mH | | 80 | mJ | |
| Repetitive avalanche current | I _{AR} | Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical 12 | | А | | |

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ROHS COMPLIANT



ISHA

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VS-175BGQ030HF4

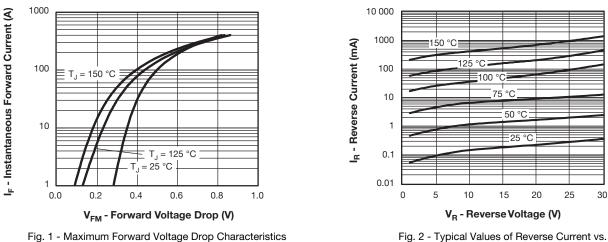
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| ELECTRICAL SPECIFICATIONS | | | | | | |
|--------------------------------|--------------------------------|--|---------------------------|------|------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | | TYP. | MAX. | UNITS |
| | | 100 A | T _{.1} = 25 °C | 0.47 | 0.49 | v |
| Forward voltage drop | V _{FM} ⁽¹⁾ | 175 A | $1_{\rm J} = 25$ C | 0.55 | 0.59 | |
| Forward voltage drop | VFM ⁽¹⁾ | 100 A | T 450.00 | 0.36 | 0.39 | |
| | | 175 A | - T _J = 150 °C | 0.47 | 0.52 | |
| | | T _J = 125 °C, V _R = 15 V | | 160 | 220 | |
| Poverse leekage ourrent | . (1) | T _J = 150 °C, V _R = 30 V | | 1400 | 2000 | m 4 |
| Reverse leakage current | I _{RM} ⁽¹⁾ | T _J = 25 °C | | 1.3 | 4.5 | - mA |
| | | T _J = 125 °C | $V_R = Rated V_R$ | 450 | 650 | |
| Maximum junction capacitance | CT | V_{R} = 5 V_{DC} , (test signal range 100 kHz to 1 MHz), 25 °C | | 85 | 00 | pF |
| Typical series inductance | Ls | Measured from tab to mounting plane 3 | | .5 | nH | |
| Maximum voltage rate of change | dV/dt | Rated V _R 10 000 V | | | V/µs | |

Note

⁽¹⁾ Pulse width < 300 μ s, duty cycle < 2 %

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | |
|--|---------|-----------------------------------|---|-------------|------------------|--|
| PARAMETER | | SYMBOL | SYMBOL TEST CONDITIONS | | UNITS | |
| Maximum junction and temperature range | storage | T _J , T _{Stg} | | -55 to +150 | °C | |
| Maximum thermal resis junction to case | tance, | R _{thJC} DC operation | | 0.35 | °C/W | |
| Typical thermal resistar case to heatsink | ice, | R _{thCS} | Mounting surface, smooth and greased | 0.20 | | |
| Approximate weight | | | | 5 | g | |
| Approximate weight | | | | 0.18 | oz. | |
| minimum | | | | 1.2 (10) | N · m | |
| Mounting torque | maximum | | | 2.4 (20) | (lbf \cdot in) | |
| Marking device | | | Case style PowerTab [®] 175BGC | | Q030H | |



Reverse Voltage

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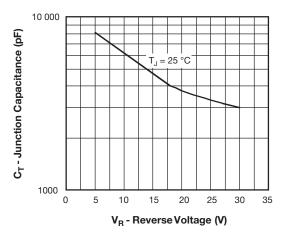


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

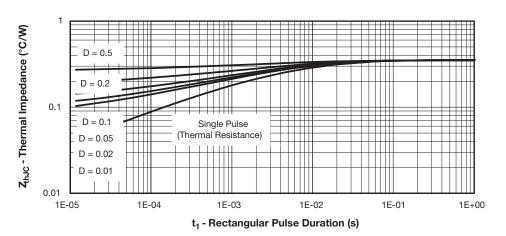
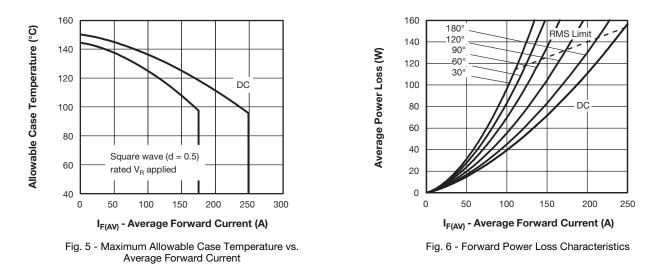


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics



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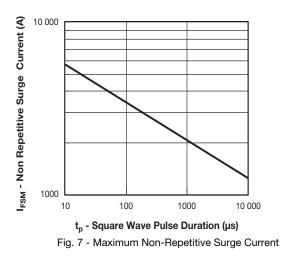
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ORDERING INFORMATION TABLE

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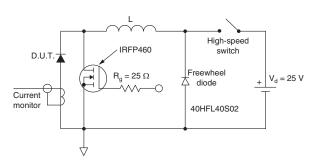


Fig. 8 - Unclamped Inductive Test Circuit

Note

- ⁽¹⁾ Formula used: $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$; $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ \mathsf{(I}_{\mathsf{F}(\mathsf{AV})} / \mathsf{D}) \ \mathsf{(see fig. 6)}; \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ \mathsf{(1 - D)}; \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \end{array}$
 - rated V_R

(Pb)-free

| Device code | VS- | 175 | BGQ | 030 | н | F4 |
|-------------|--|----------------------------------|---|---|-------------------------------------|----|
| | 1 | 2 | 3 | 4 | 5 | 6 |
| | 1 - 2 - 3 - 4 - 5 - 6 - | Cur Ess Volt H = Env | hay Sem rent ratii sential pa tage rati AEC-Q vironmer = RoHS | ng (175 art numk ng (030 101 qua ntal digit | = 175 A ber = 30 V) lified | v) |

| ORDERING INFORMATION (Example) | | | | | |
|--------------------------------|------------------|------------------------|-------------------------|--|--|
| PREFERRED P/N | QUANTITY PER T/R | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION | | |
| VS-175BGQ030HF4 | 25 | 375 | Antistatic plastic tube | | |

| LINKS TO RELATED DOCUMENTS | | | | |
|-------------------------------------|--------------------------|--|--|--|
| Dimensions www.vishay.com/doc?95240 | | | | |
| Part marking information | www.vishay.com/doc?95467 | | | |
| SPICE model | www.vishay.com/doc?95427 | | | |
| Application note | www.vishay.com/doc?95179 | | | |

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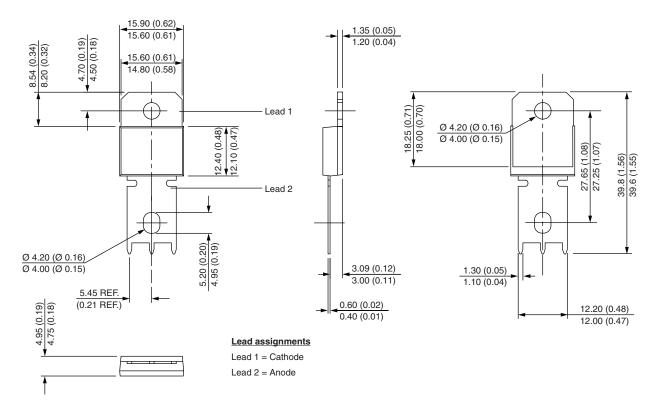
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Outline Dimensions

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DIMENSIONS in millimeters (inches)



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